

## Medium-Power Complementary Silicon Transistors

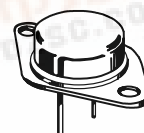
... for use as output devices in complementary general purpose amplifier applications.

- High DC Current Gain —  $h_{FE} = 6000$  (Typ) @  $I_C = 3.0$  Adc
- Monolithic Construction with Built-in Base-Emitter Shunt Resistors

**NPN**  
**MJ1000**  
**MJ1001\***

\*Motorola Preferred Device

**10 AMPERE  
DARLINGTON  
POWER TRANSISTORS  
COMPLEMENTARY  
SILICON  
60–80 VOLTS  
90 WATTS**



**CASE 1-07  
TO-204AA  
(TO-3)**

### MAXIMUM RATINGS

Rating	Symbol	MJ1000	MJ1001	Unit
Collector-Emitter Voltage	$V_{CEO}$	60	80	Vdc
Collector-Base Voltage	$V_{CB}$	60	80	Vdc
Emitter-Base Voltage	$V_{EB}$	5.0		Vdc
Collector Current	$I_C$	10		Adc
Base Current	$I_B$	0.1		Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	90 0.515		Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-55 to +200		$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.94	$^\circ\text{C/W}$

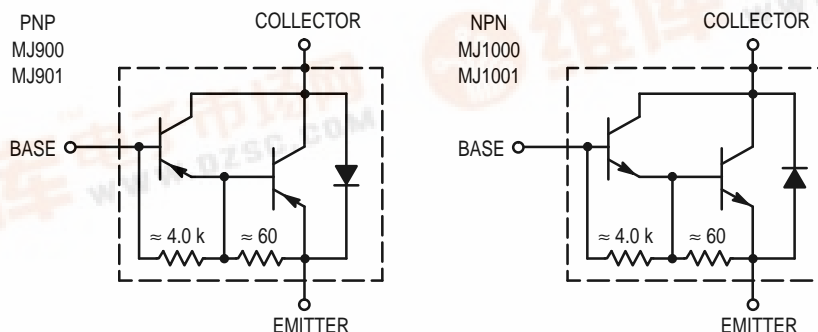


Figure 1. Darlington Circuit Schematic

Preferred devices are Motorola recommended choices for future use and best overall value.

# MJ1000 MJ1001

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector-Emitter Breakdown Voltage <sup>(1)</sup> ( $I_C = 100\text{ mAdc}$ , $I_B = 0$ )	MJ1000 MJ1001	$V_{(BR)CEO}$	60 80	— —	Vdc
Collector Emitter Leakage Current ( $V_{CB} = 60\text{ Vdc}$ , $R_{BE} = 1.0\text{ k ohm}$ ) ( $V_{CB} = 80\text{ Vdc}$ , $R_{BE} = 1.0\text{ k ohm}$ ) ( $V_{CB} = 60\text{ Vdc}$ , $R_{BE} = 1.0\text{ k ohm}$ , $T_C = 150^\circ\text{C}$ ) ( $V_{CB} = 80\text{ Vdc}$ , $R_{BE} = 1.0\text{ k ohm}$ , $T_C = 150^\circ\text{C}$ )	MJ1000 MJ1001 MJ1000 MJ1001	$I_{CER}$	— — — —	1.0 1.0 5.0 5.0	mAdc
Emitter Cutoff Current ( $V_{BE} = 5.0\text{ Vdc}$ , $I_C = 0$ )		$I_{EBO}$	—	2.0	mAdc
Collector Emitter Leakage Current ( $V_{CE} = 30\text{ Vdc}$ , $I_B = 0$ ) ( $V_{CE} = 40\text{ Vdc}$ , $I_B = 0$ )	MJ1000 MJ1001	$I_{CEO}$	— —	500 500	$\mu\text{Adc}$
<b>ON CHARACTERISTICS</b>					
DC Current Gain <sup>(1)</sup> ( $I_C = 3.0\text{ Adc}$ , $V_{CE} = 3.0\text{ Vdc}$ ) ( $I_C = 4.0\text{ Adc}$ , $V_{CE} = 3.0\text{ Vdc}$ )		$h_{FE}$	1000 750	— —	—
Collector Emitter Saturation Voltage <sup>(1)</sup> ( $I_C = 30\text{ Adc}$ , $I_B = 12\text{ mAdc}$ ) ( $I_C = 8.0\text{ Adc}$ , $I_B = 40\text{ mAdc}$ )		$V_{CE(sat)}$	— —	2.0 4.0	Vdc
Base Emitter Voltage <sup>(1)</sup> ( $I_C = 3.0\text{ Adc}$ , $V_{CE} = 3.0\text{ Vdc}$ )		$V_{BE(on)}$	—	2.5	Vdc

(1) Pulse Test: Pulse Width  $\leq 300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

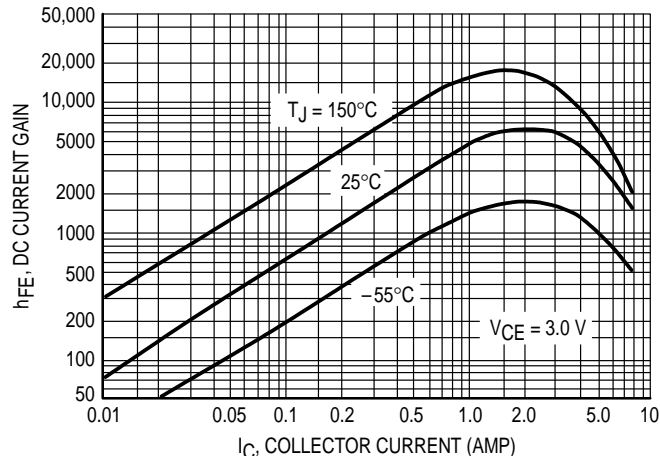


Figure 2. DC Current Gain

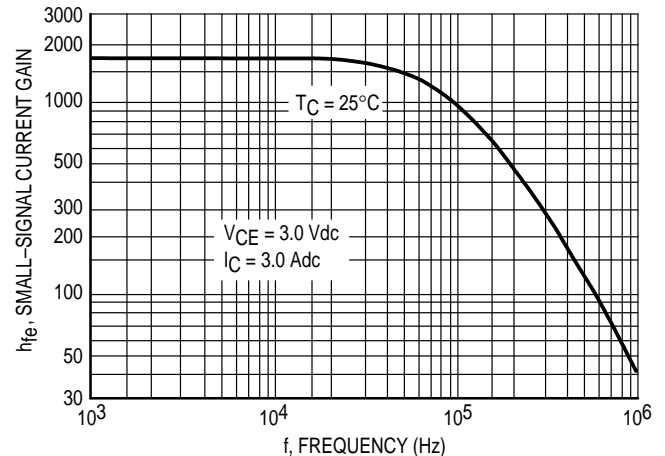


Figure 3. Small-Signal Current Gain

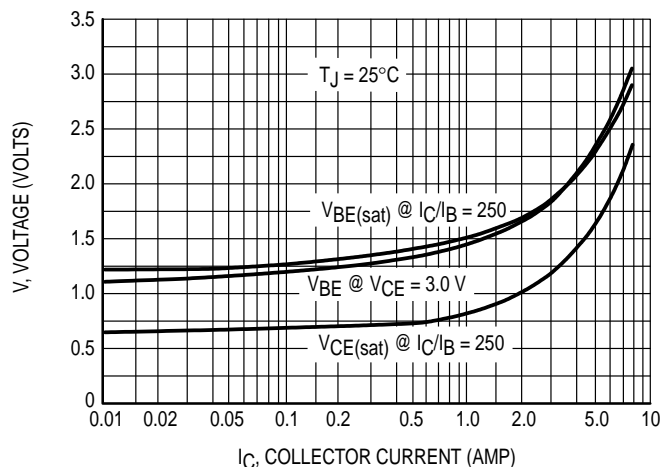


Figure 4. "On" Voltages

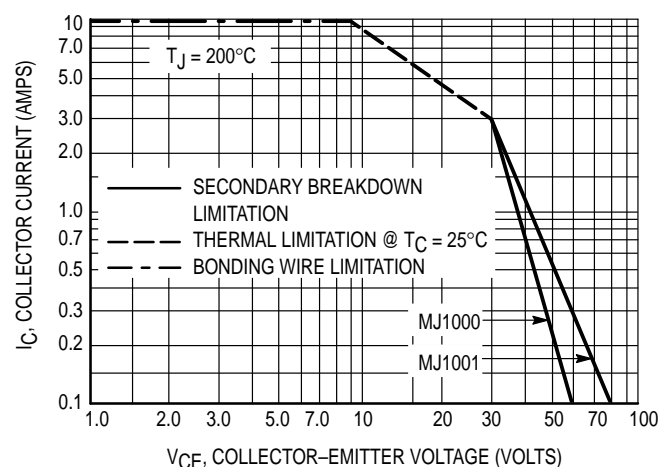


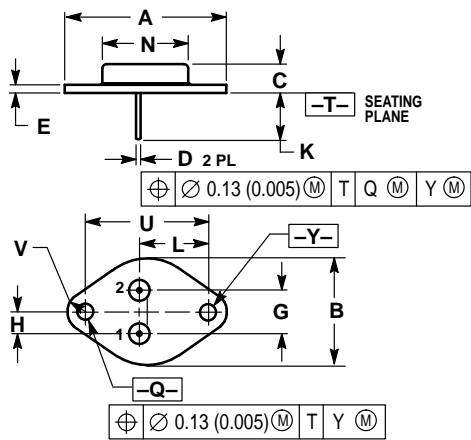
Figure 5. DC Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and secondary breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; e.g., the transistor must not be subjected to greater

dissipation than the curves indicate.

At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

PACKAGE DIMENSIONS




- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B		1.050		26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N		0.830		21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

STYLE 1:  
PIN 1. BASE  
2. EMITTER  
CASE: COLLECTOR

CASE 1-07  
TO-204AA (TO-3)  
ISSUE Z

## MJ1000 MJ1001

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